IXYS

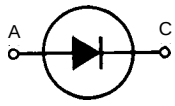
Super Fast Recovery Diode

DSDI 60

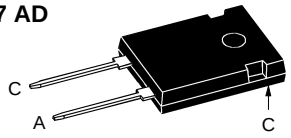
I_{FAVM} = 63 A
V_{RRM} = 1400-1800 V
t_{rr} = 40 ns

Preliminary Data

V_{RSM} V	V_{RRM} V	Type
1400	1400	DSDI 60-14A
1600	1600	DSDI 60-16A
1800	1800	DSDI 60-18A



TO-247 AD



A = Anode, C = Cathode

Symbol	Test Conditions		Maximum Ratings	
I_{FRMS}	$T_{VJ} = T_{VJM}$		100	A
I_{FAVM} ①	T_C = 60°C; rectangular, d = 0.5		63	A
I_{FRM}	t_P < 10 µs; rep. rating, pulse width limited by T_{VJM}		800	A
I_{FSM}	T_{VJ} = 45°C;	t = 10 ms (50 Hz), sine	500	A
		t = 8.3 ms (60 Hz), sine	540	A
	T_{VJ} = 150°C;	t = 10 ms (50 Hz), sine	450	A
		t = 8.3 ms (60 Hz), sine	480	A
I^2t	T_{VJ} = 45°C	t = 10 ms (50 Hz), sine	1250	A^2s
		t = 8.3 ms (60 Hz), sine	1200	A^2s
	T_{VJ} = 150°C;	t = 10 ms (50 Hz), sine	1000	A^2s
		t = 8.3 ms (60 Hz), sine	950	A^2s
T_{VJ}			-40...+150	°C
T_{VJM}			150	°C
T_{stg}			-40...+150	°C
P_{tot}	T_C = 25°C		416	W
M_d	Mounting torque		0.8...1.2	Nm
Weight			6	g

Symbol	Test Conditions		Characteristic Values typ.	max.	
I_R	T_{VJ} = 25°C	$V_R = V_{RRM}$	1	2	mA
	T_{VJ} = 25°C	$V_R = 0.8 \cdot V_{RRM}$	0.5		mA
	T_{VJ} = 125°C	$V_R = 0.8 \cdot V_{RRM}$	3		mA
V_F	I_F = 70 A;	T_{VJ} = 125°C	2.6		V
		T_{VJ} = 25°C		4.1	V
V_{T0}	For power-loss calculations only			1.9	V
r_T	$T_{VJ} = T_{VJM}$			10	mΩ
R_{thJC}				0.4	K/W
R_{thCK}			0.25		K/W
t_{rr}	I_F = 1 A; -di/dt = 200 A/µs; V_R = 30 V; T_{VJ} = 25°C		40		ns
t_{rr}	I_F = 70 A; -di/dt = 500 A/µs; V_R = 1000 V;		300		ns
I_{RM}	T_{VJ} = 25°C		60		A
t_{rr}	I_F = 70 A; -di/dt = 500 A/µs; V_R = 1000 V;		400		ns
I_{RM}	T_{VJ} = 125°C		85		A

① I_{FAVM} rating includes reverse blocking losses at T_{VJM}, $V_R = 0.8\ V_{RRM}$, duty cycle d = 0.5
Data according to IEC 60747
IXYS reserves the right to change limits, test conditions and dimensions

Features

- International standard package JEDEC TO-247 AD
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I_{RM}-values
- Soft recovery behaviour
- Epoxy meets UL 94V-0
- Creepage distance between leads 8.5 mm

Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

Dimensions

See DSEI 60-12 on page D5 - 27

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